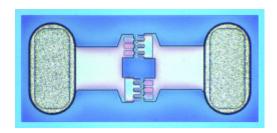


# Agilent HSCH-9551 GaAs Schottky Diode Antiparallel Pair

Data Sheet



Chip Size:  $620 \times 325 \,\mu\text{m} \,(24.4 \times 12.8 \,\text{mils})$ 

Chip Size Tolerance:  $\pm 10 \,\mu\text{m} (\pm 0.4 \,\text{mils})$ Chip Thickness:  $100 \,\mu\text{m} (4 \,\text{mils})$ 

Chip Thickness Tolerance:  $\pm$  15  $\mu$ m ( $\pm$  0.6 mils) Bond Pad Sizes:  $100 \times 200 \ \mu$ m ( $3.9 \times 7.9 \ mils$ )

## Specifications

The HSCH-9551 is an integrated antiparallel pair of GaAs Schott-ky barrier diodes. It is a beamless
 V<sub>F</sub> (1 mA): 700-800 mV
 V<sub>F</sub> (10 mA): 800-850 mV

• R<sub>S</sub> (5 mA): <6 Ω

• C<sub>J</sub> (per diode): <0.050 pF

#### **Assembly Techniques**

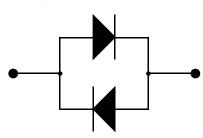
GaAs Schottky diodes are ESD sensitive. ESD preventive measures must be employed in all aspects of storage, handling, and assembly.

ESD precautions, handling considerations, die attach and bond-

#### **Features**

- Low Junction Capacitance

   typically 40 fF
- Low Series Resistance typically 3  $\Omega$
- Large bond pads suitable for automated wire-bonding or flip-chip assembly
- · Polyimide scratch protection



ing methods are critical factors in successful diode performance and reliability.

Agilent application note #54, "GaAs MMIC ESD, Die Attach and Bonding Guidelines" provides basic information on these subjects.

### Applications

Description

The HSCH-9551 is a high-performance millimeter wave diode that can be used as a sub-harmonically pumped mixer or frequency multiplier in microwave and millimeter wave transceivers.

version of the HSCH-9251 anti-

parallel pair beam lead diode.

This data sheet contains a variety of typical and guaranteed performance data. The information supplied should not be interpreted as a complete list of circuit specifications. In this data sheet the term *typical* refers to the 50th percentile performance. For additional information contact your local Agilent Technologies sales representative.



Notes:

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